







Instructor: Nasser Ismail 2nd 2015-2016





Instructor: Nasser Ismail 2nd 2015-2016

Piezoresistive sensors

- A piezoresistive sensor is made from semiconductor material in which a ptype region has been diffused into an ntype base. The resistance of this varies greatly when the sensor is compressed or stretched.
- This is frequently used as a strain gauge, where it produces a significantly higher gauge factor than that given by metal wire or foil gauges. Also, measurement uncertainty can be reduced to ±0.1%.
- It is also used in semiconductordiaphragm pressure sensors and in semiconductor accelerometers.





















Instructor: Nasser Ismail 2nd 2015-2016

Hall Effect Sensors

The Hall effect refers to the <u>potential difference</u> (Hall voltage) on the opposite sides of an <u>electrical</u> <u>conductor</u> through which an <u>electric current</u> is flowing, created by a <u>magnetic field</u> applied <u>perpendicular</u> to the current. <u>Edwin Hall</u> discovered this effect in 1879.

Hall effect diagram, showing electron flow (rather than <u>conventional current</u>).

Legend:

- 1. Electrons
- 2. Hall element, or Hall sensor
- 3. Magnets; 4. Magnetic field ;
- 5. Power source

Description:



In drawing "A", the Hall element takes on a negative charge at the top edge (symbolised by the blue color) and positive at the lower edge (red color).



- □ A Hall-effect sensor is a device that is used to measure the magnitude of a magnetic field.
- It consists of a conductor carrying a current that is aligned orthogonally with the magnetic field.
- This produces a transverse voltage difference across the device that is directly proportional to the magnetic field strength.
- For an excitation current I and magnetic field strength B, the output voltage is given by
- □ V= KIB, where K is known as the Hall constant.
- The conductor in Hall-effect sensors is usually made from a semiconductor material as opposed to a metal, because a larger voltage output is produced for a magnetic field of a given size.







Piezoelectricity

- Piezoelectricity is the ability of some materials (notably crystals and certain ceramics) to generate an electric potential in response to applied mechanical stress. This may take the form of a separation of electric charge across the crystal lattice. If the material is not shortcircuited, the applied charge induces a voltage across the material.
- The word is derived from the <u>Greek</u> *piezein*, which means to squeeze or press.
- The piezoelectric effect is reversible in that materials exhibiting the *direct piezoelectric effect* (the production of electricity when stress is applied) also exhibit the *converse piezoelectric effect* (the production of stress and/or strain when an electric field is applied).
- For example, <u>lead zirconate titanate</u> crystals will exhibit a maximum shape change of about 0.1% of the original dimension.



Piezoelectric transducers

- Piezoelectric transducers are made from piezoelectric materials. These have an asymmetrical lattice of molecules that distorts when a mechanical force is applied to it.
- This distortion causes a reorientation of electric charges within the material, resulting in a relative displacement of positive and negative charges.
- □ The charge displacement induces surface charges on the material of opposite polarity between the two sides. By implanting electrodes into the surface of the material, these surface charges can be measured as an output voltage. For a rectangular block of material, the induced voltage is given by:

$$V = \frac{kFd}{A}$$

where F is the applied force, A is the area of the material, d is the thickness of the material and k is the piezoelectric constant. The polarity of the induced voltage depends on whether the material is compressed or stretched.







Light energy

- For a sensor, we're interested in the light power that falls on a unit area, and how well the sensor converts that into a signal.
- A common unit is the lux which measures apparent brightness (power multiplied by the human eye's sensitivity).
- 1 lux of yellow light is about 0.0015 W/m².
- 1 lux of green light (50% eff.) is 0.0029 W/m².
- Sunlight corresponds to about 50,000 lux
- Artificial light typically 500-1000 lux





Light Detectors

- Photocells and phototransistors are particularly sensitive in the infrared region, and so are ideal partners for infrared LED and laser diode sources.
- Air-path optical sensors are commonly used to measure proximity, translational motion, rotational motion and gas concentration.

Light sensors – high end At the cutting edge of light sensor sensitivity are Avalanche photodiodes. Large voltages applied to these diodes accelerate electrons to "collide" with the semiconductor lattice, creating more charges. These devices have quantum efficiencies around 90% and extremely low noise. They are now made with large collection areas and known as LAAPDs (Large-Area Avalanche Photo-Diode)









OPTICAL SENSOR MEASURANDS				
TEMI	PERATURE	CHEMICAL SPECIES		
PRES	SSURE	FORCE		
FLOV	V	RADIATION		
LIQU	ID LEVEL	рН		
DISP	LACEMENT	HUMIDITY		
VIBR	ATION	STRAIN		
ROTA	ATION	VELOCITY		
MAG	NETIC FIELDS	ELECTRIC FIELDS		
ACCI	ELERATION	ACOUSTIC FIELDS		

Optical sensors

- Light sources suitable for transmission across an air path include tungstenfilament lamps, laser diodes and lightemitting diodes (LEDs).
- ❑ However, as the light from tungsten lamps is usually in the visible part of the light frequency spectrum, it is prone to interference from the sun and other sources.
- Hence, infrared LEDs or infrared laser diodes are usually preferred.
- These emit light in a narrow frequency band in the infrared region and are not affected by sunlight



Light Detectors • Air-path optical sensors are commonly used to measure proximity, translational motion, rotational motion and gas concentration.





OPTICAL SENSOR MEASURANDS				
	TEMPERATURE	CHEMICAL SPECIES		
	PRESSURE	FORCE		
	FLOW	RADIATION		
	LIQUID LEVEL	рН		
	DISPLACEMENT	HUMIDITY		
	VIBRATION	STRAIN		
	ROTATION	VELOCITY		
	MAGNETIC FIELDS	ELECTRIC FIELDS		
	ACCELERATION	ACOUSTIC FIELDS		











